

UNISONIC TECHNOLOGIES CO., LTD

MGBR20U50 Preliminary DIODE

MOS GATED BARRIER RECTIFIER

DESCRIPTION

The UTC MGBR20U50 is a surface mount mos gated barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed etc.

The UTC MGBR20U50 suitable for supply applications.

FEATURES

- * Ultra low forward voltage drop
- * High switching speed

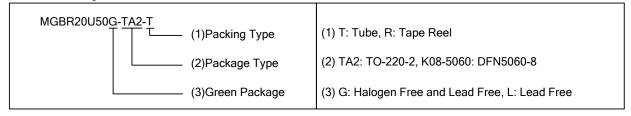
SYMBOL



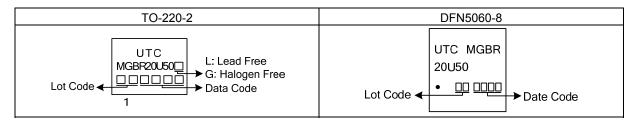
ORDERING INFORMATION

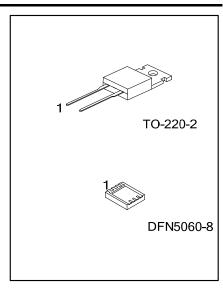
Ordering Number		Dookogo	Pin Assignment							Dooking		
Lead Free	Halogen Free	Package	1	2	3	4	5	6	7	8	Packing	
MGBR20U50L-TA2-T	MGBR20U50G-TA2-T	TO-220-2	Κ	Α	ı	-	ı	ı	-	-	Tube	
MGBR20U50L-K08-5060-R	MGBR20U50G-K08-5060-R	DFN5060-8	Α	Α	Α	NC	Κ	Κ	Κ	Κ	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



MARKING





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■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage	V_{RM}	50	V
Working Peak Reverse Voltage	V_{RWM}	50	V
Peak Repetitive Reverse Voltage	V_{RRM}	50	V
Average Rectified Forward Current (Rated VR-20Khz Square Wave) - 50% Duty Cycle	Io	20	Α
Peak Forward Surge Current - 1/2 60hz	I _{FSM}	300	Α
Peak Repetitive Reverse Surge Current (2uS-1Khz)	I _{RRM}	2	Α
Maximum Rate of Voltage Change (at Rated V_R)	dv/dt	10000	V/µS
Operating Junction Temperature	T_J	-65 ~ +150	°C
Storage Junction Temperature	T _{STG}	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
lunation to Ambient	TO-220-2	0	60	°C // //
Junction to Ambient	DFN5060-8	θJA	72	°C/W

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.50mA	50			V
Forward Voltage	I V _{EM}	I _F =20A, T _J =25°C			0.48	V
		I _F =20A, T _J =125°C			0.43	V
Reverse Current (Note 1)	I PM	V _R =50V, T _J =25°C			500	μA
		V _R =50V, T _J =125°C			100	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

^{2.} Thermal resistance junction to case mounted on heatsink.

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